# TOSHIBA

# PHOTO RELAY

## Telecommunication

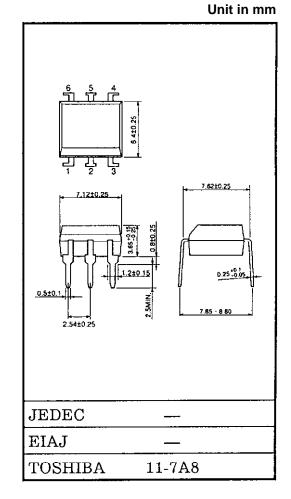
## **Data Acquisition**

#### **Measurement Instrumentation**

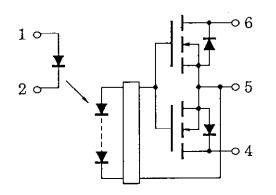
The Toshiba TLP596G consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a six lead plastic DIP package. The TLP596G is a bi-directional switch which can replace mechanical relays in many applications.

- Peak Off-State Voltage :
- On-State Current
- : 400V (Min.)
  - : 120mA (Max.) (A Connection) : 30Ω (Max.) (A Connection)
- On-State Resistance Insulation Thickness
- : 0.4mm (Max.)
- Isolation VoltageUL Recognized
- : 2500Vrms (Min.) : UL1577, File No. E67349
- Trigger LED Current (Ta = 25°C)

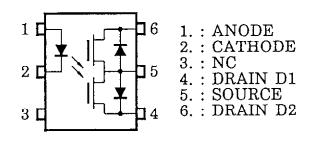
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Lead Form Options	31-32
Tape and Reel	39-40



# Pin Configuration (Top View)



#### Schematic



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	TRIGGER LED C	URRENT (mA)	
CLASSIFICATION (Note 1)	@I <sub>ON</sub> = 1	20mA	MARKING OF CLASSIFICATION
	MIN.	MAX.	
(IFT2)	-	2	T2
Standard	-	5	T2, Blank

Note 1: Application type name for certification test, please use standard product type name, i.e., TLP596G (IFT2): TLP596G

## Maximum Ratings (Ta = 25°C)

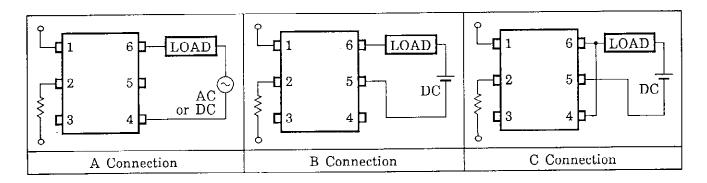
	CHARACTERISTIC			RATING	UNIT	
Forward Current			١ <sub>F</sub>	50	mA	
	Forward Current Derating (Ta $\ge 25^{\circ}$ C)	∆l <sub>F</sub> /°C	-0.5	mA/°C		
LED	Peak Forward Current (100µs pulse, 100pps)		I <sub>FP</sub>	1	A	
	Reverse Voltage		V <sub>R</sub>	5	V	
	Junction Temperature		Тј	125	°C	
Off-State Output Terminal Voltage				400	V	
	On-State RMS Current	A Connection		120	mA	
		B Connection	I <sub>ON</sub>	150		
DETECTOR		C Connection		200		
DETECTOR	On-State Current Derating (Ta ≥ 25°C)	A Connection		-1.2	mA/°C	
		B Connection	∆l <sub>ON</sub> /°C	-1.5		
		C Connection		-2.0	1	
	Junction Temperature		tj	125	°C	
Storage Temperature Range			T <sub>stg</sub>	-55~100	°C	
Operating Temperature Range			T <sub>opr</sub>	-20~85	°C	
Lead Soldering Temperature (10s)			T <sub>sol</sub>	260	°C	
Isolation Voltag	Isolation Voltage (AC, 1 min., R.H. $\leq$ 60%) (Note 1)			2500	V <sub>rms</sub>	

Note 1:Device considered a two terminal device: pins 1, 2 and 3 shorted together, and pins 4, 5 and 8 shorted together.

# **Recommended Operating Conditions**

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MX.	UNIT
Supply Voltage	V <sub>D</sub>	_	-	320	V
Forward Current	١ <sub>F</sub>	7.5	15	25	mA
On-State Current	I <sub>ON</sub>	-	-	120	mA
Operating Temperature	T <sub>opr</sub>	-20	-	80	°C

#### **Circuit Connections**



## Individual Electrical Characteristics (Ta = -25°C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.*	MX.	UNIT
	Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 10mA	1.0	1.15	1.3	V
LED	Reverse Current	I <sub>R</sub>	$V_R = 5V$	-	-	10	μA
	Capacitance	CT	V = 0, f = 1MHz	-	30	-	pF
DETECTOR	Off-State Current	I <sub>OFF</sub>	V <sub>OFF</sub> = 400V	-	-	1	μA
	Capacitance	C <sub>OFF</sub>	V = 0, f = 1MHz	-	-	-	pF

#### Coupled Electrical Characteristics (Ta = 25°C)

CHARACTER	RISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MX.	UNIT
Trigger LED Current		I <sub>FT</sub>	I <sub>ON</sub> = 120mA	-	1	5	mA
	A Connection	R <sub>ON</sub>	I <sub>ON</sub> = 120mA, I <sub>F</sub> = 10mA	-	20	30	
On-State Resistance	B Connection		I <sub>ON</sub> = 150mA, I <sub>F</sub> = 10mA	-	12	20	Ω
	C Connection		I <sub>ON</sub> = 200mA, I <sub>F</sub> = 10mA	-	6	10	

# Isolation Characteristics (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MX.	UNIT
Capacitance Input to Output	C <sub>S</sub>	V <sub>S</sub> = 0, f = 1MHz	-	0.8	_	pF
Isolation Resistance	R <sub>S</sub>	$V_{S} = 500V, R.H. \le 60\%$	5 x 10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
Isolation Voltage	BV <sub>S</sub>	AC, 1 minute	2500	-	_	V
		AC, 1 second in oil	-	5000	_	V <sub>rms</sub>
		DC, 1 minute in oil	-	5000	_	V <sub>dc</sub>

## Switching Characteristics (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MX.	UNIT
Turn-on Time	t <sub>on</sub>	R <sub>L</sub> = 200Ω	-	_	2	ms
Turn-off Time	t <sub>off</sub>	V <sub>DD</sub> = 20mA, I <sub>F</sub> = 10mA	-	_	2	1115

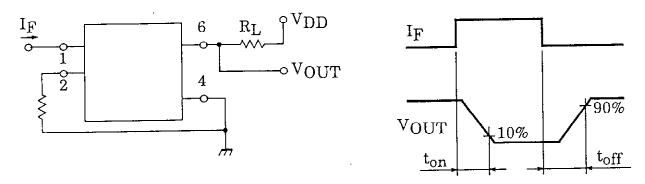


Figure 1. Switching Time Test Circuit

